# Precision Ionization Calibrations of Silicon Skipper CCDs for Dark Matter Detection

#### New Perspectives 2023



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#### Dark matter detection with silicon CCDs



## Skipper CCDs

- Measures charge multiple times when compared to conventional CCDs
- Can achieve single electron resolution
- Per each Non Destructive Charge Measurement [NDCM] the readout noise reduces by 1/√N<sub>skips</sub>







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#### Detection

Dark matter interaction in the CCDs can occur in 2 ways:

- Electron recoil: Resulting in the excitation of electrons from the silicon atomic and band structure. The recoil energy is directly proportional to the number of electron hole pairs generated
  Nuclear recoil: When a DM particle
- Nuclear recoil: When a DM particle interacts with the silicon nucleus, part of the nuclear recoil energy gets transferred to ionisation of electrons. A quenching factor quantifies the relationship between the nuclear recoil energy and the ionization electrons.



## Compton scattering

• Signals from background gamma rays can mimic DM electron recoil signals.

γ

e-

 Hence it is important to understand the detector response to gammas low energies

#### Compton scattering in Silicon



2.5

### Experimental Setup and Data collection

- Skipper CCD with 1024 x 6176 pixels is used as the silicon target detector
- <sup>241</sup>Am was used as the gamma ray source, emitting 59.54 keV γ rays was mounted to illuminate the backside of the CCD
- The CCD was cooled to 126 K and under pressure of 10<sup>-7</sup> mbar
- Images with N<sub>skip</sub> = 64 were taken with a total exposure of 105.5 days
- Background images with no source and serial register images with source but clocking the CCD in the opposite direction were taken



## Analysis

- Images were processed so as to reconstruct clusters of pixels associated with each event to obtain their full energy.
- Events occurring at the serial register present as *horizontal* clusters throughout the image posing as significant background.
- Exposure normalized background and serial register data were subtracted from the source data to obtain the final spectrum.



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## Results

- The final spectrum was compared with GEANT4 simulations.
- While the K-step showed perfect agreement with GEANT4, discrepancies arose at lower energies near the L<sub>1</sub> and L<sub>2,3</sub> steps.
- An *ab initio* calculation framework called FEFF was used to model the spectrum, which showed agreements with our measured spectrum.
- Hence we have successfully measured the compton scattering spectrum in Silicon down to 23 eV.
- This result will be used to model the uncertainties in the gamma backgrounds for DAMIC-M DM searches.



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## Silicon nuclear recoil measurement

- Measurement of nuclear recoil in silicon produced by low energy neutrons (<22.6 keV)
- <sup>124</sup>Sb-<sup>9</sup>Be photoneutron source was used to produce the necessary neutrons
- Measurement with conventional CCDs found deviations from the lindhard model



### Nuclear recoil measurement setup

- Similar setup to that of Compton measurement was used.
- A lead castle was built to house the photoneutron source to shield the CCD from high energy gammas.
- The source setup was alternated between SbBe and SbAl to account for background due to gammas.



## Preliminary results



Background subtracted nuclear recoil ionization spectrum



Flux of neutrons seen at the CCD as simulated by GEANT4

Obtaining the quenching factor is work in progress

## Conclusions

- We have measured Compton scattering down to 23 eV
- Obtaining the nuclear recoil quenching factor at energies < 20 eV is in progress.
- These precision ionization measurements at low energies aid in calibrating the detector behaviour to backgrounds and improve limits in DM detections.



